Selection Guide

Part Number	Package	Packing	Ambient Temperature (°C)
A6276EA-T	24-pin DIP	15 per tube	–40 to 85
~~A6276ELPTR-T*~~	24-pin TSSOP	4000 per reel	–40 to 85
A6276ELWTR-T	24-pin SOICW	1000 per reel	–40 to 85
~~A6276SLWTR-T*~~	24-pin SOICW	1000 per reel	–20 to 85

*Variant is in production but has been determined to be LAST TIME BUY. This classification indicates that the variant is obsolete and notice has been given. Sale of the variant is currently restricted to existing customer applications. The variant should not be purchased for new design applications because of obsolescence in the near future. Samples are no longer available. Status date change November 1, 2008. Deadline for receipt of LAST TIME BUY orders is April 25, 2009.

Absolute Maximum Ratings*

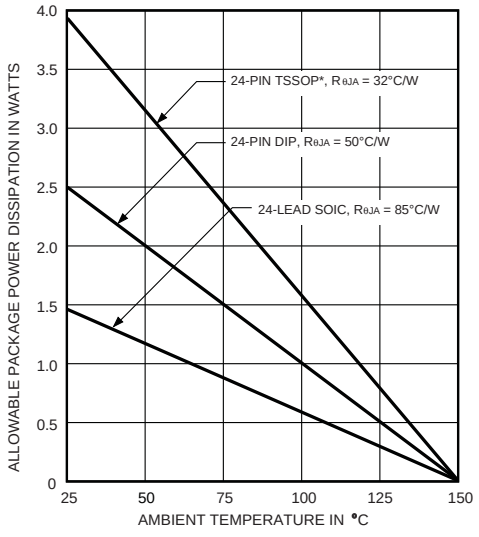
Characteristic	Symbol	Notes	Rating	Units
Supply Voltage	V_{DD}		7.0	V
Output Voltage	V_O		–0.5 to 17	V
Input Voltage	V_{ROUT}		–0.4 to V_{DD} + 0.4	V
Output Current	I_O		90	mA
Ground Current	I_{GND}		1475	mA
Operating Ambient Temperature	T_A	Range S	–20 to 85	°C
		Range E	–40 to 85	°C
Maximum Junction Temperature	T_J(max)		150	°C
Storage Temperature	T_{stg}		–55 to 150	°C

*Caution: These CMOS devices have input static protection (Class 2) but are still susceptible to damage if exposed to extremely high static electrical charges.

Thermal Characteristics may require derating at maximum conditions, see application information

Characteristic	Symbol	Test Conditions*	Value	Units
Package Thermal Resistance	$R_{\theta JA}$	Package A, 1-layer PCB based on JEDEC standard	50	°C/W
		Package LP, 2-layer PCB with 3.8 in² copper area each side	32	°C/W
		Package LW, 1-layer PCB based on JEDEC standard	85	°C/W

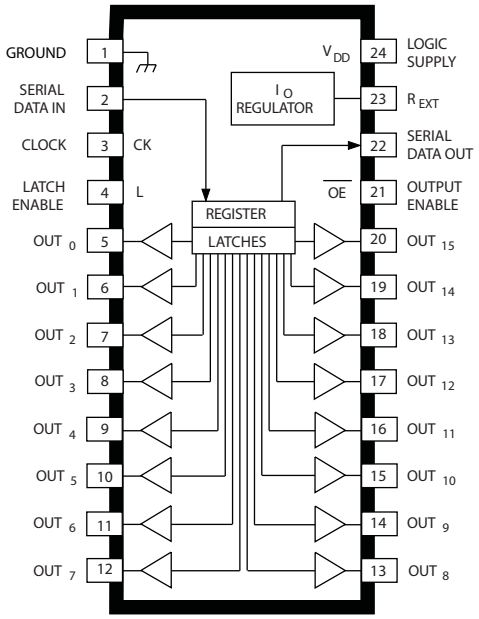
*Additional thermal information available on the Allegro website



*Mounted on single-layer, two-sided PCB, with 3.8 in² copper area each side; additional information on Allegro Web site

Pin-out Diagram

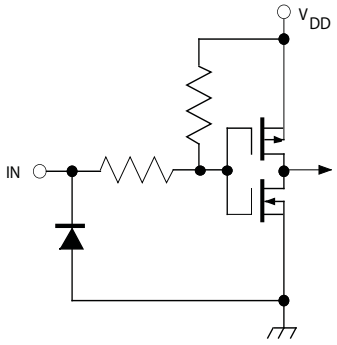
(A, LP, and LW packages)



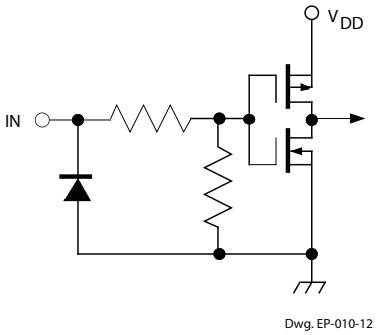
Terminal Description

Terminal No.	Terminal Name	Function
1	GND	Reference terminal for control logic.
2	SERIAL DATA IN	Serial-data input to the shift-register.
3	CLOCK	Clock input terminal for data shift on rising edge.
4	LATCH ENABLE	Data strobe input terminal; serial data is latched with high-level input.
5-20	OUT_{0-15}	The 16 current-sinking output terminals.
21	OUTPUT ENABLE	When (active) low, the output drivers are enabled; when high, all output drivers are turned OFF (blanked).
22	SERIAL DATA OUT	CMOS serial-data output to the following shift-register.
23	R_{EXT}	An external resistor at this terminal establishes the output current for all sink drivers.
24	SUPPLY	(V_{DD}) The logic supply voltage (typically 5 V).

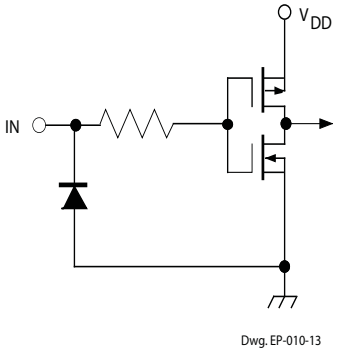
Allegro MicroSystems, Inc.
115 Northeast Cutoff
Worcester, Massachusetts 01615-0036 U.S.A.
1.508.853.5000; www.allegromicro.com



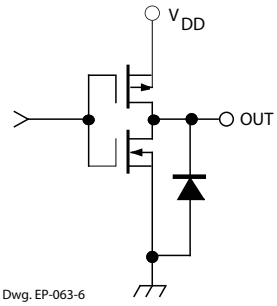
OUTPUT ENABLE (active low)



LATCH ENABLE



CLOCK and SERIAL DATA IN



SERIAL DATA OUT

TRUTH TABLE

Serial Data Input	Clock Input	Shift Register Contents	Serial Data Output	Latch Enable Input	Latch Contents	Output Enable Input	Output Contents
		I_1 I_2 I_3 ... I_{N-1} I_N			I_1 I_2 I_3 ... I_{N-1} I_N		I_1 I_2 I_3 ... I_{N-1} I_N
H		H R_1 R_2 ... R_{N-2} R_{N-1}	R_{N-1}				
L		L R_1 R_2 ... R_{N-2} R_{N-1}	R_{N-1}				
X		R_1 R_2 R_3 ... R_{N-1} R_N	R_N				
		X X X ... X X	X	L	R_1 R_2 R_3 ... R_{N-1} R_N		
		P_1 P_2 P_3 ... P_{N-1} P_N	P_N	H	P_1 P_2 P_3 ... P_{N-1} P_N	L	P_1 P_2 P_3 ... P_{N-1} P_N
					X X X ... X X	H	H H H ... H H

L = Low Logic (Voltage) Level H = High Logic (Voltage) Level X = Irrelevant P = Present State R = Previous State

ELECTRICAL CHARACTERISTICS at T_A = +25°C, V_{DD} = 5 V (unless otherwise noted).

Characteristic	Symbol	Test Conditions	Limits			
			Min.	Typ.	Max.	Unit
Supply Voltage Range	V_{DD}	Operating	4.5	5.0	5.5	V
Under-Voltage Lockout	$V_{DD(UV)}$	V_{DD} = 0 5 V	3.4	–	4.0	V
Output Current (any single output)	I_O	V_{CE} = 0.7 V, R_{EXT} = 250 Ω	64.2	75.5	86.8	mA
		V_{CE} = 0.7 V, R_{EXT} = 470 Ω	34.1	40.0	45.9	mA
Output Current Matching (difference between any two outputs at same V_{CE})	ΔI_O	0.4 V $V_{CE(A)}$ = $V_{CE(B)}$ 0.7 V:				
		R_{EXT} = 250 Ω	–	±1.5	±6.0	%
		R_{EXT} = 470 Ω	–	±1.5	±6.0	%
Output Leakage Current	I_{CEX}	V_{OH} = 15 V	–	1.0	5.0	µA
Logic Input Voltage	V_{IH}		0.7V_{DD}	–	V_{DD}	V
	V_{IL}		GND	–	0.3V_{DD}	V
SERIAL DATA OUT Voltage	V_{OL}	I_{OL} = 500 µA	–	–	0.4	V
	V_{OH}	I_{OH} = -500 µA	4.6	–	–	V
Input Resistance	R_I	ENABLE Input, Pull Up	150	300	600	kΩ
		LATCH Input, Pull Down	100	200	400	kΩ
Supply Current	$I_{DD(OFF)}$	R_{EXT} = open, V_{OE} = 5 V	–	0.8	1.4	mA
		R_{EXT} = 470 Ω, V_{OE} = 5 V	3.5	6.0	8.0	mA
		R_{EXT} = 250 Ω, V_{OE} = 5 V	6.5	11	15	mA
	$I_{DD(ON)}$	R_{EXT} = 470 Ω, V_{OE} = 0 V	7.0	13	20	mA
		R_{EXT} = 250 Ω, V_{OE} = 0 V	10	22	32	mA

Typical Data is at V_{DD} = 5 V and is for design information only.

SWITCHING CHARACTERISTICS at T_A = 25°C, V_{DD} = V_{IH} = 5 V, V_{CE} = 0.4 V, V_{IL} = 0 V, R_{EXT} = 470 Ω, I_O = 40 mA, V_L = 3 V, R_L = 65 Ω, C_L = 10.5 pF.

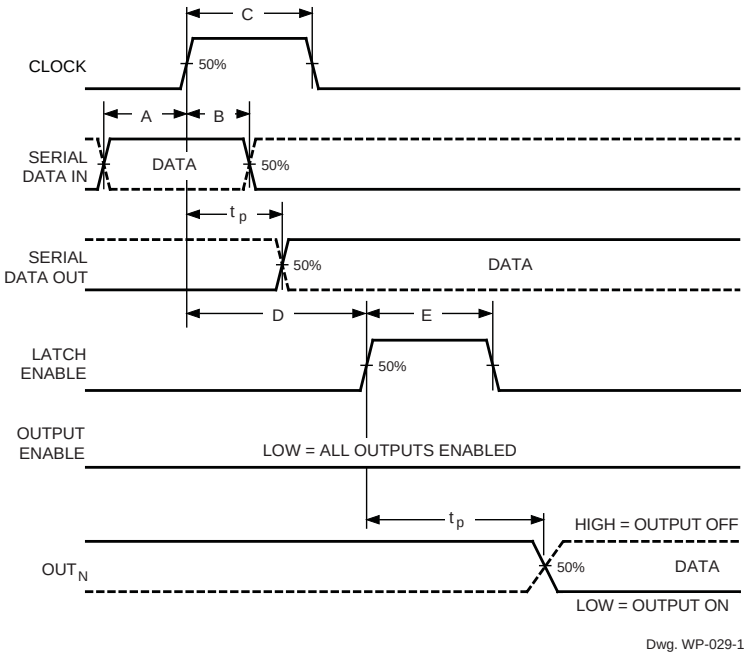
Characteristic	Symbol	Test Conditions	Limits			
			Min.	Typ.	Max.	Unit
Propagation Delay Time	t_{pHL}	CLOCK-OUT$_n$	–	350	1000	ns
		LATCH-OUT$_n$	–	350	1000	ns
		ENABLE-OUT$_n$	–	350	1000	ns
		CLOCK-SERIAL DATA OUT	–	40	–	ns
Propagation Delay Time	t_{pLH}	CLOCK-OUT$_n$	–	300	1000	ns
		LATCH-OUT$_n$	–	300	1000	ns
		ENABLE-OUT$_n$	–	300	1000	ns
		CLOCK-SERIAL DATA OUT	–	40	–	ns
Output Fall Time	t_f	90% to 10% voltage	150	350	1000	ns
Output Rise Time	t_r	10% to 90% voltage	150	300	600	ns

RECOMMENDED OPERATING CONDITIONS

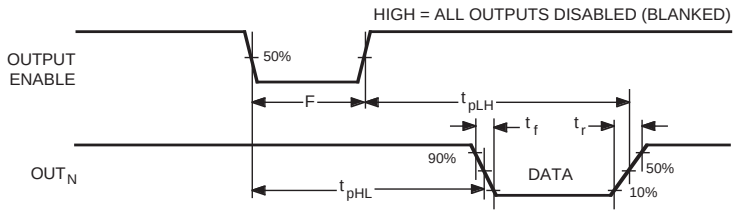
Characteristic	Symbol	Conditions	Min.	Typ.	Max.	Unit
Supply Voltage	V_{DD}		4.5	5.0	5.5	V
Output Voltage	V_O		–	1.0	4.0	V
Output Current	I_O	Continuous, any one output	–	–	90	mA
	I_{OH}	SERIAL DATA OUT	–	–	-1.0	mA
	I_{OL}	SERIAL DATA OUT	–	–	1.0	mA
Logic Input Voltage	V_{IH}		0.7V_{DD}	–	V_{DD} + 0.3	V
	V_{IL}		-0.3	–	0.3V_{DD}	V
Clock Frequency	f_{CK}	Cascade operation	–	–	10	MHz

TIMING REQUIREMENTS and SPECIFICATIONS

(Logic Levels are V_{DD} and Ground)



Dwg. WP-029-1



Dwg. WP-030-1A

A. Data Active Time Before Clock Pulse (Data Set-Up Time), $t_{su(D)}$ ..... **50 ns**
B. Data Active Time After Clock Pulse (Data Hold Time), $t_{h(D)}$ ..... **20 ns**
C. Clock Pulse Width, $t_{w(CK)}$ ..... **50 ns**
D. Time Between Clock Activation and Latch Enable, $t_{su(L)}$ ..... **100 ns**
E. Latch Enable Pulse Width, $t_{w(L)}$ ..... **100 ns**
F. Output Enable Pulse Width, $t_{w(OE)}$ ..... **4.5 µs**

NOTE: Timing is representative of a 10 MHz clock. Significantly higher speeds are attainable.

Max. Clock Transition Time, t_r or t_f ..... **10 µs**

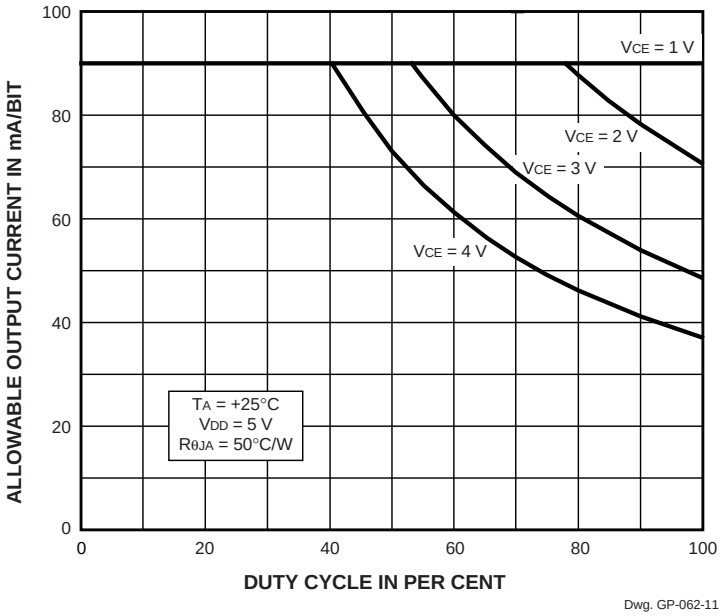
Serial data present at the input is transferred to the shift register on the logic 0-to-logic 1 transition of the CLOCK input pulse. On succeeding CLOCK pulses, the registers shift data information towards the SERIAL DATA OUTPUT. The serial data must appear at the input prior to the rising edge of the CLOCK input waveform.

Information present at any register is transferred to the respective latch when the LATCH ENABLE is high (serial-to-parallel conversion). The latches continue to accept new data as long as the LATCH ENABLE is held high. Applications where the latches are bypassed (LATCH ENABLE tied high) will require that the OUTPUT ENABLE input be high during serial data entry.

When the OUTPUT ENABLE input is high, the output sink drivers are disabled (OFF). The information stored in the latches is not affected by the OUTPUT ENABLE input. With the OUTPUT ENABLE input low, the outputs are controlled by the state of their respective latches.

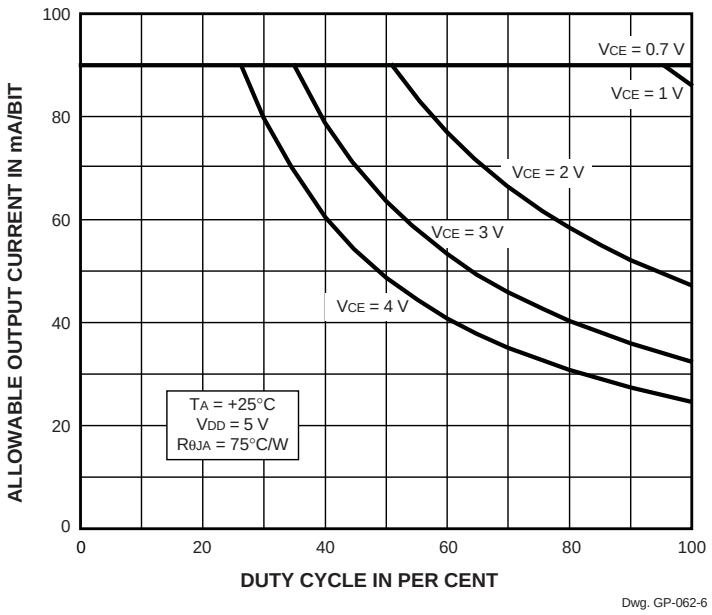
ALLOWABLE OUTPUT CURRENT AS A FUNCTION OF DUTY CYCLE

A6276EA

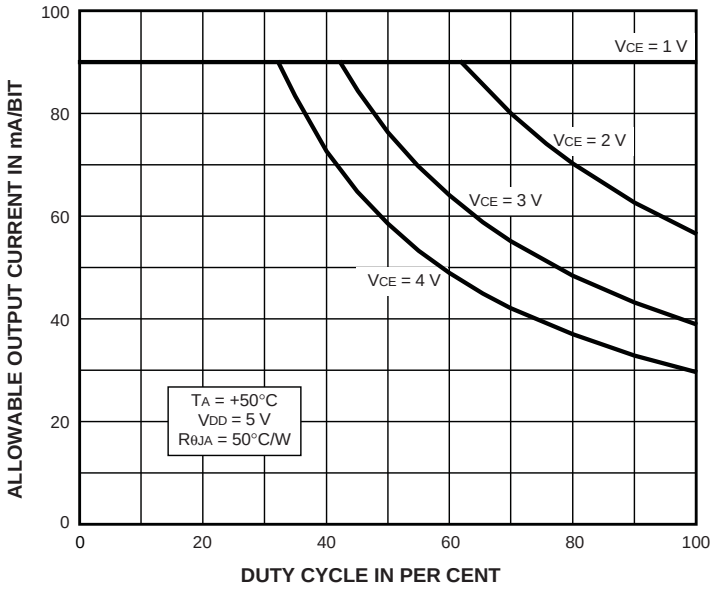


Dwg. GP-062-11

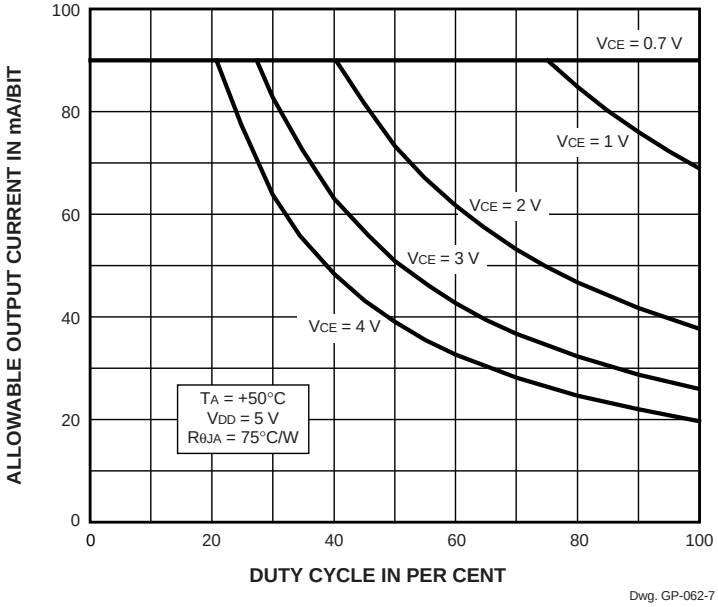
A6276ELW



Dwg. GP-062-6



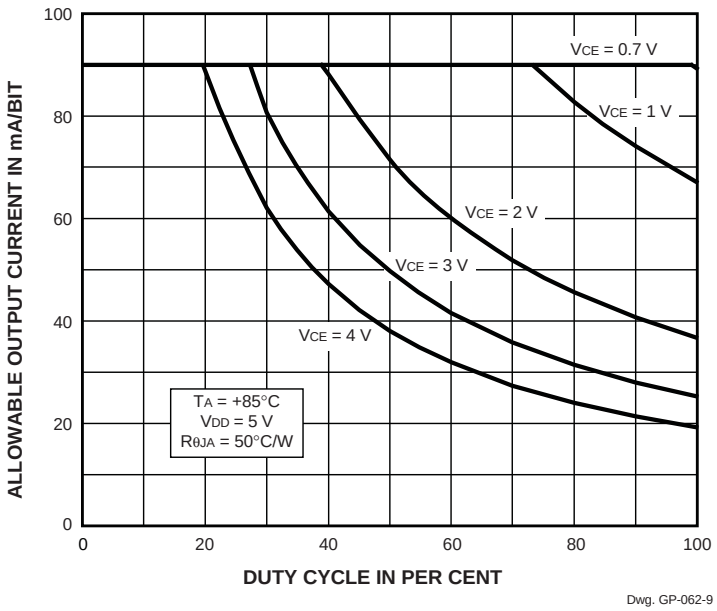
Dwg. GP-062-10



Dwg. GP-062-7

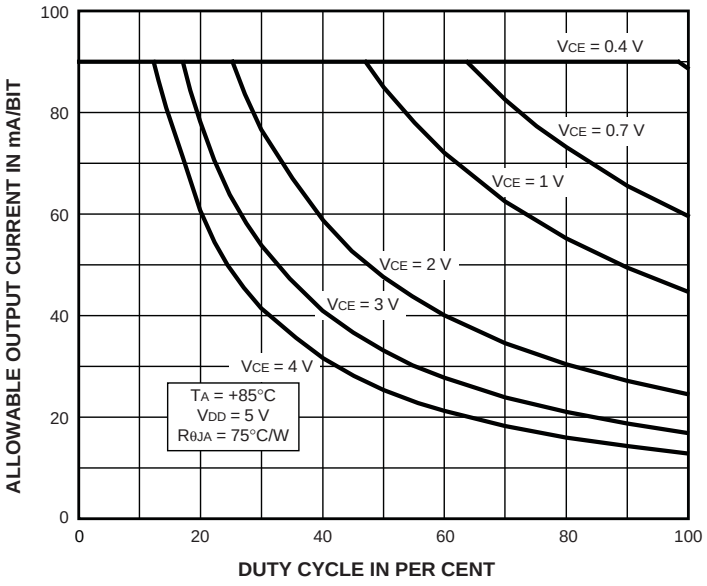
ALLOWABLE OUTPUT CURRENT AS A FUNCTION OF DUTY CYCLE (cont.)

A6276EA



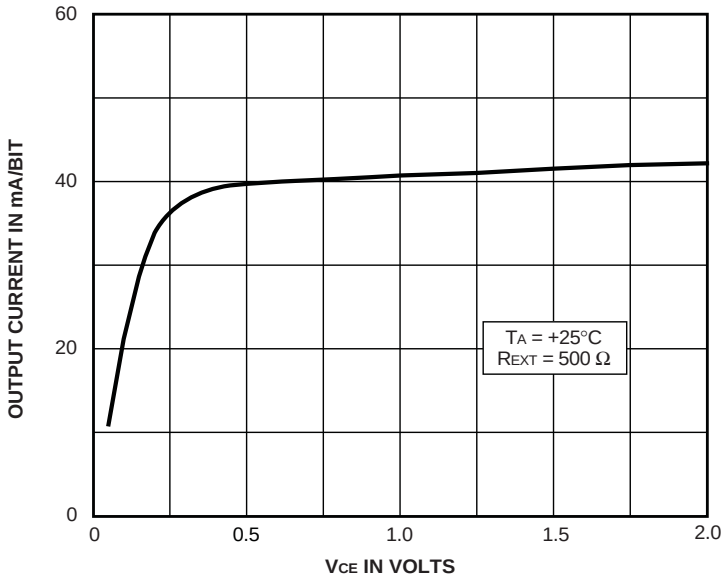
Dwg. GP-062-9

A6276ELW



Dwg. GP-062-8

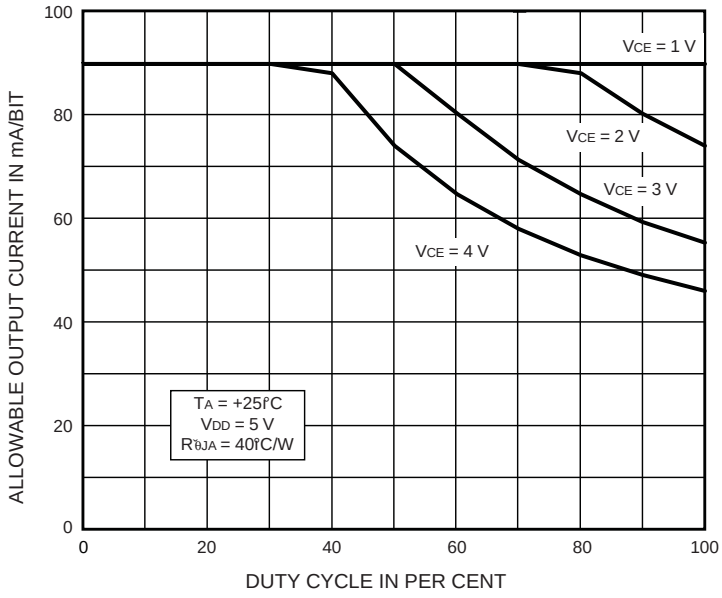
TYPICAL CHARACTERISTICS

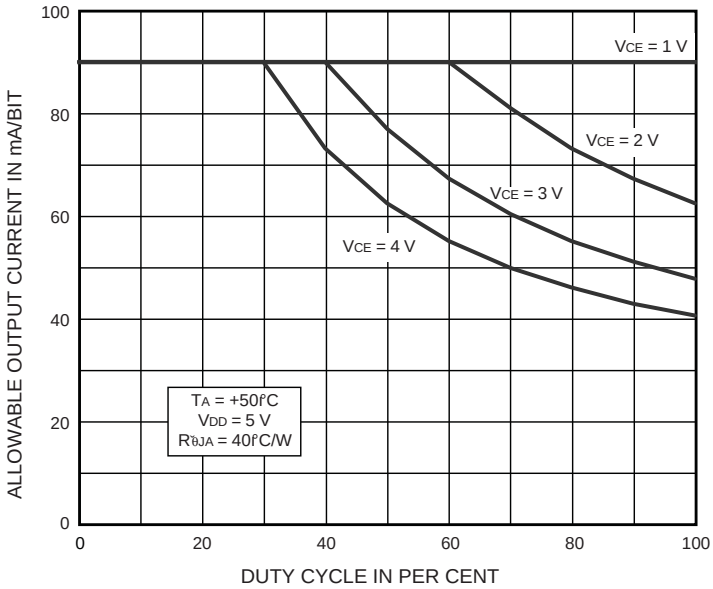


Dwg. GP-063

ALLOWABLE OUTPUT CURRENT AS A FUNCTION OF DUTY CYCLE (cont.)

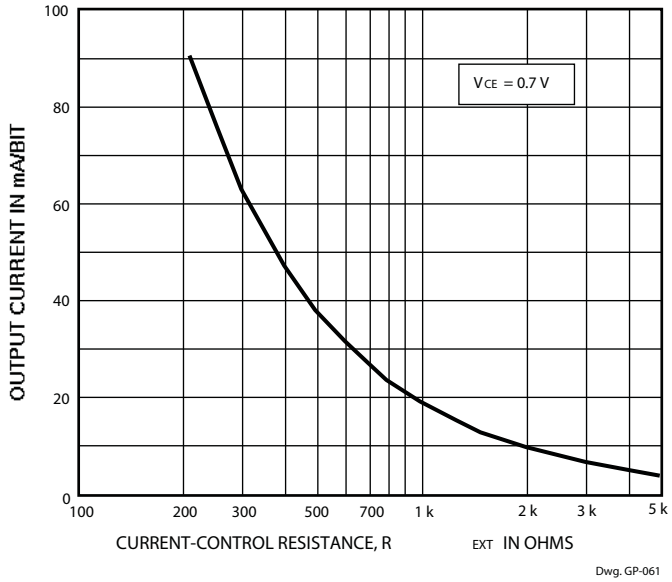
A6276ELP





Applications Information

The load current per bit (I_O) is set by the external resistor (R_{EXT}) as shown in the figure below.



Package Power Dissipation (P_D). The maximum allowable package power dissipation is determined as

$$P_D(max) = (150 - T_A)/R_{\theta JA}.$$

The actual package power dissipation is

$$P_D(act) = DC \bullet (V_{CE} \bullet I_O \bullet 16) + (V_{DD} \bullet I_{DD}) ,$$

where DC is the duty cycle.

When the load supply voltage is greater than 3 V to 5 V, considering the package power dissipating limits of these devices, or if $P_D(act) > P_D(max)$, an external voltage reducer (V_{DROP}) should be used.

Load Supply Voltage (V_{LED}). These devices are designed to operate with driver voltage drops (V_{CE}) of 0.4 V to 0.7 V with LED forward voltages (V_F) of 1.2 V to 4.0 V. If higher voltages are dropped across the driver, package power dissipation will be increased significantly. To minimize package power dissipation, it is recommended to use the lowest possible load supply voltage or to set any series dropping voltage (V_{DROP}) as

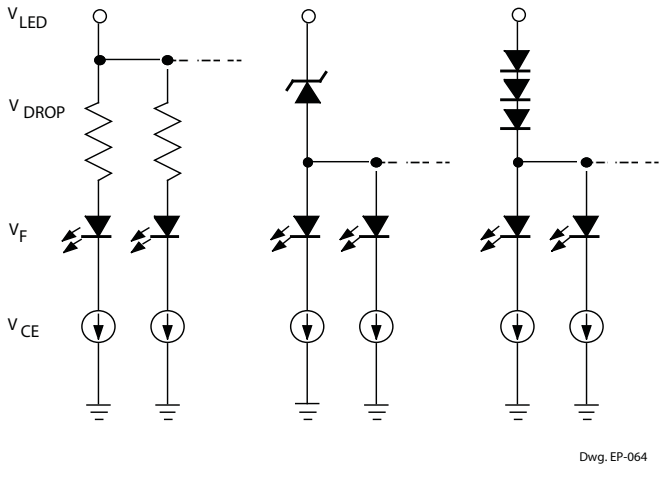
$$V_{DROP} = V_{LED} - V_F - V_{CE}$$

with $V_{DROP} = I_o \bullet R_{DROP}$ for a single driver, or a Zener diode (V_Z), or a series string of diodes (approximately 0.7 V per diode) for a group of drivers. If the available voltage source will cause unacceptable dissipation and series resistors or diode(s) are undesirable, a regulator such as the Sanken Series SAI or Series SI can be used to provide supply voltages as low as 3.3 V.

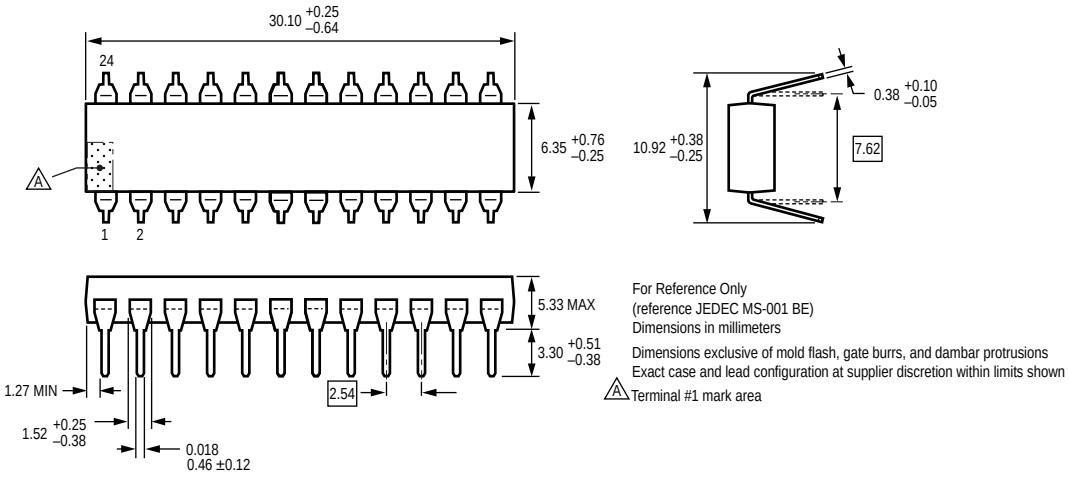
For reference, typical LED forward voltages are:

White	3.5 – 4.0 V
Blue	3.0 – 4.0 V
Green	1.8 – 2.2 V
Yellow	2.0 – 2.1 V
Amber	1.9 – 2.65 V
Red	1.6 – 2.25 V
Infrared	1.2 – 1.5 V

Pattern Layout. This device has a common logic-ground and power-ground terminal. If ground pattern layout contains large common-mode resistance, and the voltage between the system ground and the LATCH ENABLE or CLOCK terminals exceeds 2.5 V (because of switching noise), these devices may not operate correctly.



Package A, 24-pin DIP

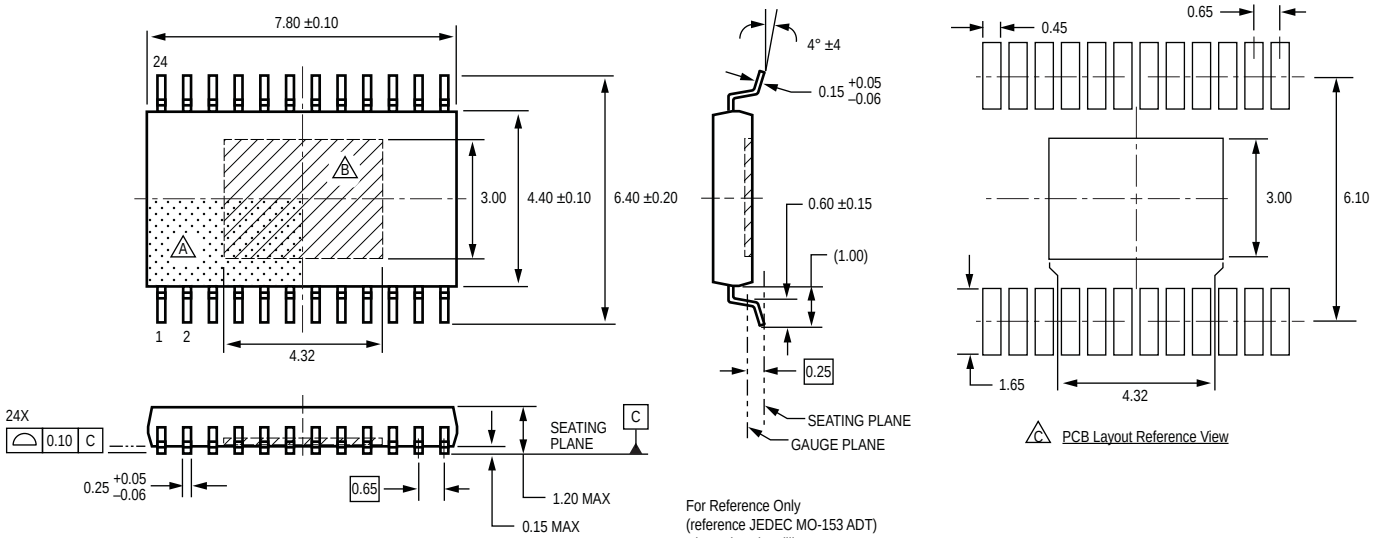


For Reference Only
(reference JEDEC MS-001 BE)
Dimensions in millimeters

Dimensions exclusive of mold flash, gate burrs, and dambar protrusions
Exact case and lead configuration at supplier discretion within limits shown

A Terminal #1 mark area

Package A, 24-pin TSSOP with exposed thermal pad



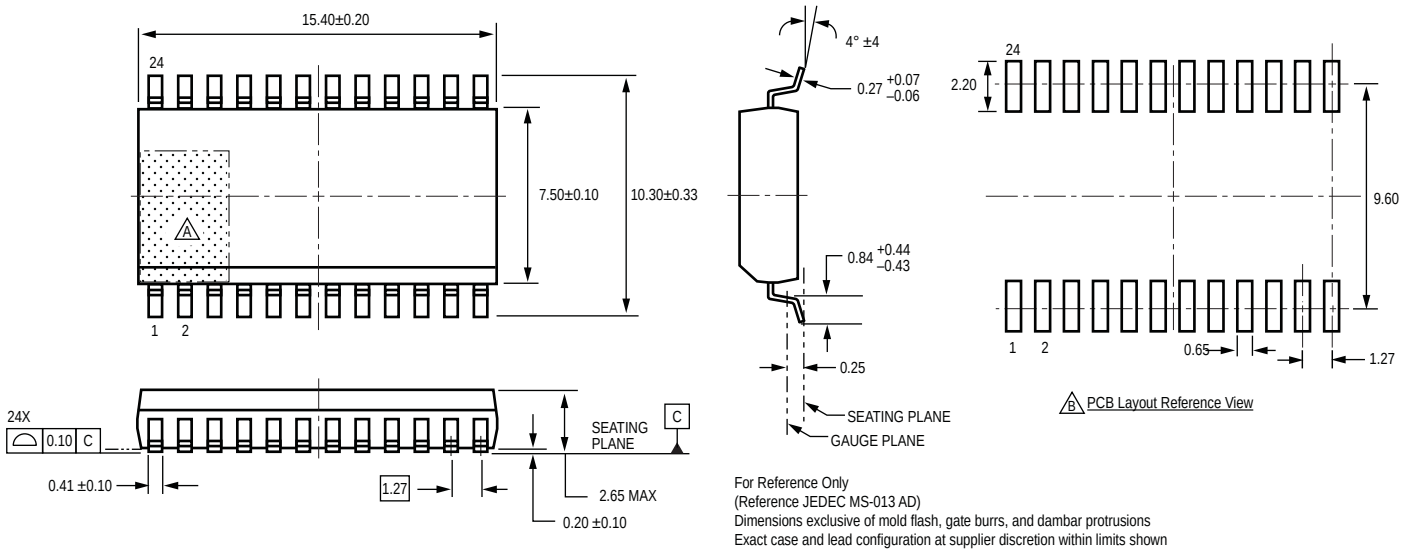
For Reference Only
(reference JEDEC MO-153 ADT)
Dimensions in millimeters
Dimensions exclusive of mold flash, gate burrs, and dambar protrusions
Exact case and lead configuration at supplier discretion within limits shown

A Terminal #1 mark area

B Exposed thermal pad (bottom surface)

C Reference land pattern layout (reference IPC7351 TSOP65P640X120-25M); all pads a minimum of 0.20 mm from all adjacent pads; adjust as necessary to meet application process requirements and PCB layout tolerances; when mounting on a multilayer PCB, thermal vias at the exposed thermal pad land can improve thermal dissipation (reference EIA/JEDEC Standard JESD51-5)

Package LW, 24-pin SOICW



For Reference Only
(Reference JEDEC MS-013 AD)
Dimensions exclusive of mold flash, gate burrs, and dambar protrusions
Exact case and lead configuration at supplier discretion within limits shown

A Terminal #1 mark area

B Reference pad layout (reference IPC SOIC127P1030X265-24M)
All pads a minimum of 0.20 mm from all adjacent pads; adjust as necessary to meet application process requirements and PCB layout tolerances

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